

#### 3.2x1.6mm SMD CHIP LED LAMP

AP3216EC

HIGH EFFICIENCY RED

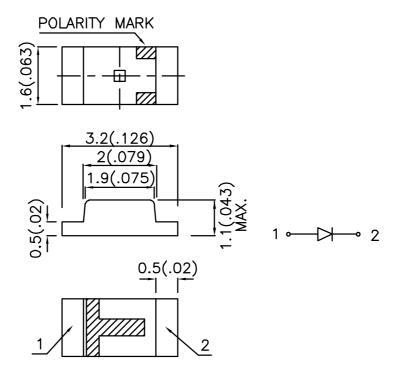
#### **Features**

- •3.2mmx1.6mm SMT LED, 1.1mm THICKNESS.
- •LOW POWER CONSUMPTION.
- •WIDE VIEWING ANGLE.
- •IDEAL FOR BACKLIGHT AND INDICATOR.
- •VARIOUS COLORS AND LENS TYPES AVAILABLE.
- •PACKAGE: 2000PCS/REEL.
- •RoHS COMPLIANT.

#### **Description**

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

## **Package Dimensions**



- Notes: 1. All dimensions are in millimeters (inches). 2. Tolerance is  $\pm 0.2 (0.008")$  unless otherwise noted. 3. Specifications are subject to change without notice.

SPEC NO: DSAD0978 **REV NO: V.5** DATE: MAR/15/2005 **PAGE: 1 OF 4** APPROVED: J. Lu **CHECKED: Allen Liu** DRAWN: W.J.ZHU ERP:1203000335

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#### **Selection Guide**

| Part No. | Dice                            | Lens Type   |      | Iv (mcd)<br>@ 20mA |         |
|----------|---------------------------------|-------------|------|--------------------|---------|
|          |                                 |             | Min. | Тур.               | 2 θ 1/2 |
| AP3216EC | HIGH EFFICIENCY RED (GaAsP/GaP) | WATER CLEAR | 4    | 12                 | 120°    |

Note

## Electrical / Optical Characteristics at Ta=25°C

| Symbol | Parameter                | Device              | Тур. | Max. | Units | Test Conditions |
|--------|--------------------------|---------------------|------|------|-------|-----------------|
| λpeak  | Peak Wavelength          | High Efficiency Red | 627  |      | nm    | IF=20mA         |
| λD     | Dominant Wavelength      | High Efficiency Red | 625  |      | nm    | IF=20mA         |
| Δλ1/2  | Spectral Line Half-width | High Efficiency Red | 45   |      | nm    | IF=20mA         |
| С      | Capacitance              | High Efficiency Red | 15   |      | pF    | VF=0V;f=1MHz    |
| VF     | Forward Voltage          | High Efficiency Red | 2.0  | 2.5  | V     | IF=20mA         |
| IR     | Reverse Current          | High Efficiency Red |      | 10   | uA    | VR = 5V         |

## Absolute Maximum Ratings at Ta=25°C

| Parameter                     | High Efficiency Red | Units |
|-------------------------------|---------------------|-------|
| Power dissipation             | 105                 | mW    |
| DC Forward Current            | 30                  | mA    |
| Peak Forward Current [1]      | 160                 | mA    |
| Reverse Voltage               | 5                   | V     |
| Operating/Storage Temperature | -40°C To +85°C      | •     |

Note:

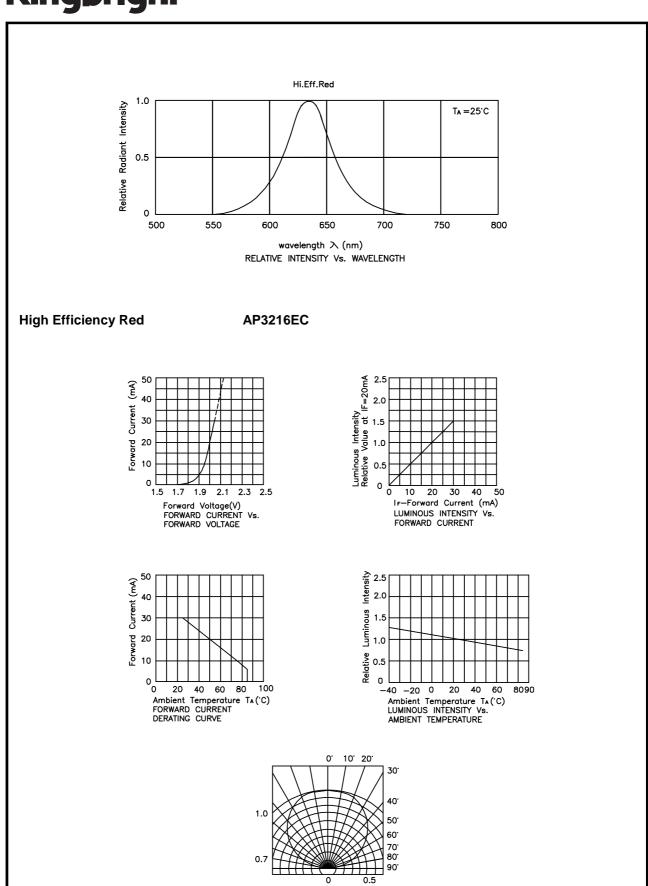
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

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 $<sup>1.\,\</sup>theta1/2$  is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

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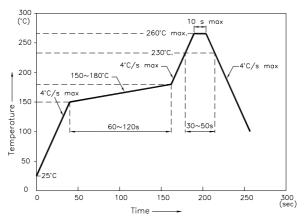
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SPATIAL DISTRIBUTION

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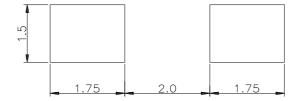
#### **AP3216EC**

Reflow Soldering Profile For Lead-free SMT Process.

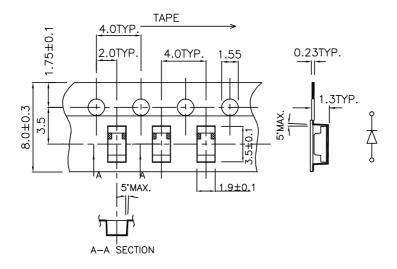


- NOTES: 1.We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C. 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
  - 3. Number of reflow process shall be 2 times or less.

#### **Recommended Soldering Pattern** (Units: mm)



## **Tape Specifications** (Units: mm)



### Remarks:

If special sorting is required (e.g. binning based on forward voltage,luminous intensity, or wavelength), the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity: +/-15%
- 3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.

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